

Schottky Rectifier ,400A

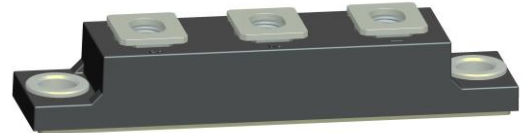
Features

- 175°C T_J operation
- Centertapmodule
- Lo forward voltage drop
- Guard ring for enhanced ruggedness and Long term reliability
- Lead(pb)-free
- Designed and qualified for industrial level

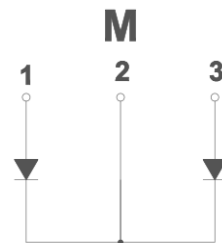
Typical Applications

- High current switching power supplies
- Plating power supplies
- UPS system
- Converters
- Freewheeling
- Welder
- Reverse battery protection

C3 Package



TO-244 (insulated)



Major Ratings and Characteristics

Symbol	Characteristics	Values	Unit
I _{F(AV)}	Rectangular waveform	400	A
V _{RRM}		100	V
I _{FSM}	T _P =5us sine	25000	A
V _F	100A _{PK} T _J =125°C(per leg)	0.55	V
T _J	Range	-55 to 175	°C

Absolute Maximum Ratings

Parameters	Symbol	Test Conditions		Values	Unit
Maximum average forward per leg Current per device	I _{F(AV)}	50% duty cycle at T _J =142°C, rectangular waveform		200	A
				400	
Maximum peak one cycle non-repetitive surge current per leg	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} Applied	25000	A
		10 ms sine or 6 ms rect. pulse		3000	
Non- repetitive avalanche energy per leg	E _{AS}	T _J =25°C, I _{AS} =13A, L=0.2mH		15	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J maximum V _A =1.5×V _{DS} typical		1	A

Electrical Specifications

Parameters	Symbol	Test Conditions		Values	Unit
Maximum forward voltage drop per leg	$V_{FM}^{(1)}$	200A	$T_J=25^{\circ}\text{C}$	0.65	A
		400A		0.85	
		200A	$T_J=125^{\circ}\text{C}$	0.55	
		400A		0.75	
Maximum reverse leakage current per leg	$I_{RM}^{(1)}$	$T_J=25^{\circ}\text{C}$	$V_R=\text{Rated } V_R$	0.5	mA
		$T_J=125^{\circ}\text{C}$		40	
Threshold voltage	$V_{F(TO)}$	$T_J= T_J \text{ Maximum}$		0.5	V
Forward slope resistance	r_t			1.08	m Ω
Maximum junction capacitance per leg	C_T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25°C		4150	pF
Typical series inductance per leg	L_S	From top of termina hole to mounting plane		6.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10000	V/ μs
Maximum RMS insulation voltage (for insulated type)	V_{isol}	Ac.50Hz; R.M.S; 1min		2500	V
		Ac.50Hz; R.M.S; 1sec		3500	

Note: (1) Pulse width < 300 μs , duty cycle < 2%

Thermal Mechanical Specifications

Parameters	Symbol	Min	Typ	Max	Unit
Maximum junction and storage temperature range	T_J, T_{Stg}	-55	—	175	$^{\circ}\text{C}$
Thermal resistance, junction to case per leg	C3(Insulated) $R_{th(J-C)}$	—	—	0.26	$^{\circ}\text{C}/\text{W}$
Thermal resistance, junction to case per module	C3(Insulated) $R_{th(C-S)}$	—	—	0.13	
Thermal resistance, case to heatsink		—	0.1	—	
Module(Approximately)	C3(Insulated) Weight	—	100	—	g
Mounting torque	To terminals(M6) M_t	4		5.8	Nm
	To heatsink(M6) M_s	4		6	

Performance Curves

Fig.1 Maximum forward voltage drop Characteristics(Per Leg)

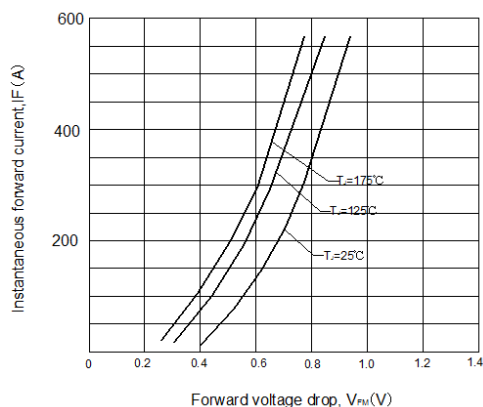


Fig.2 Typical Junction Capacitance vs reverse Voltage(Per leg)

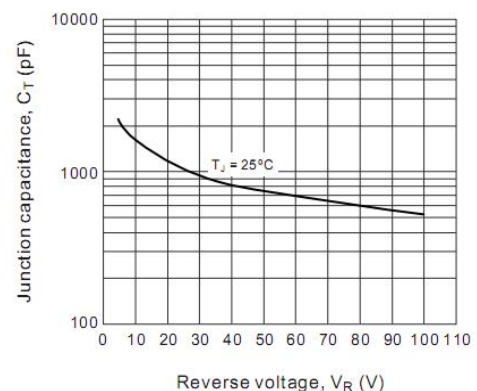


Fig.3 Maximum thermal impedance $R_{th(j-c)}$ characteristics
(Per Leg, for TO-244 insulated)

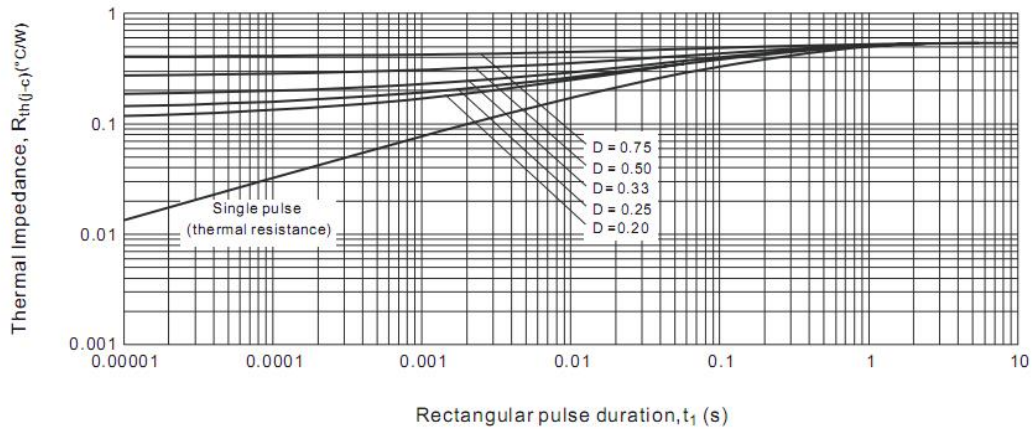


Fig.4 Maximum allowable case temperature
Vs. Average forward current (Per Leg)

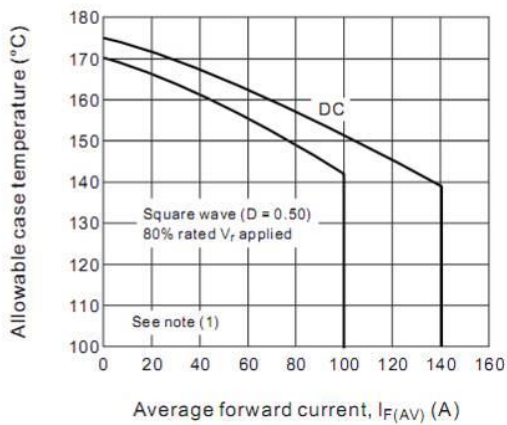


Fig.5 Forward power loss characteristics
(Per Leg)

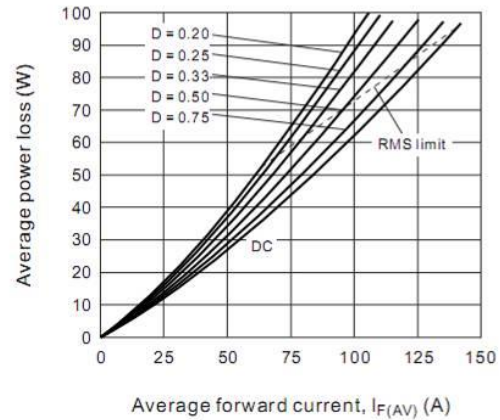


Fig.6 Maximum non-repetitive surge current
(Per Leg)

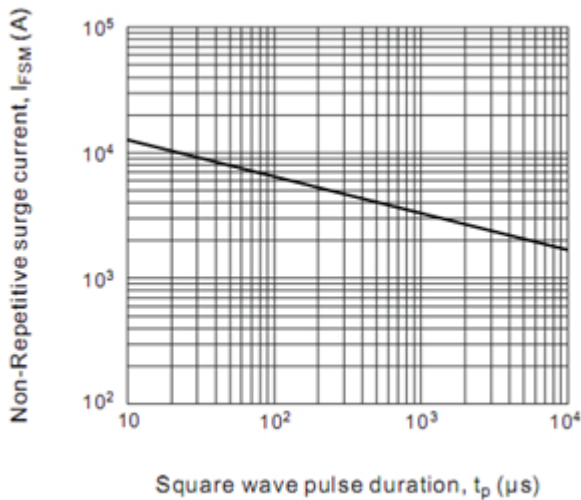
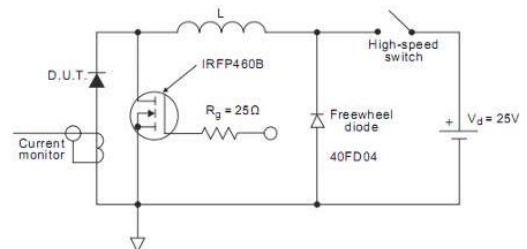


Fig.7 Unclampen Inductive test circuit



Note

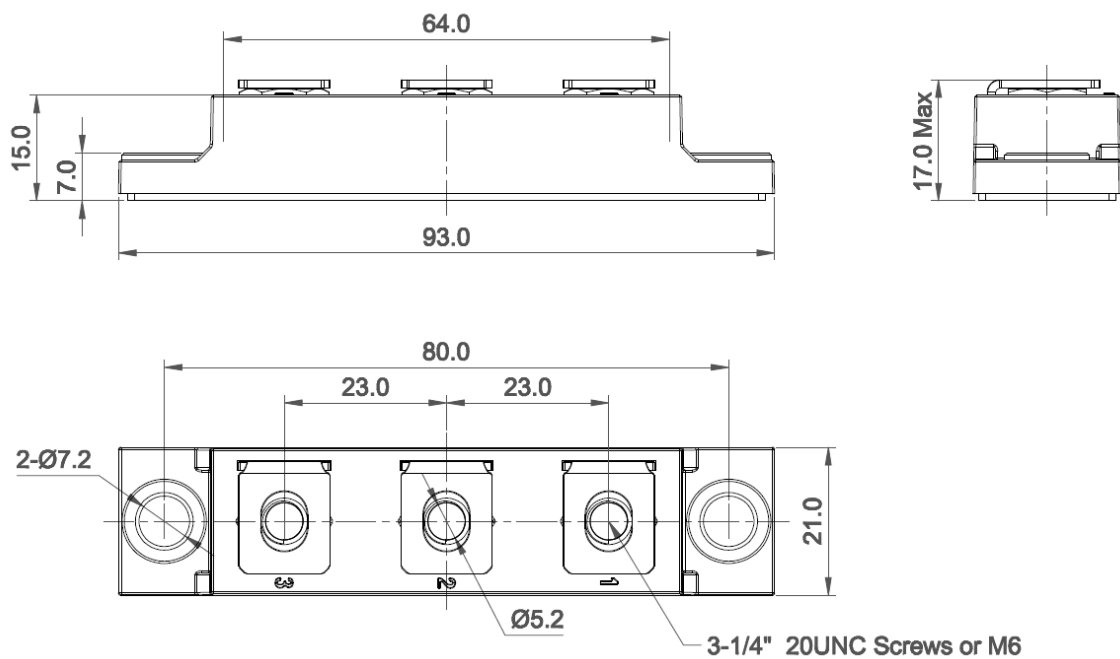
(1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{th(j-c)}$

P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig.6)

P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1-D)$; I_R at $V_{R1} = 80\%$ rated V_R

Ordering Information Tabel
Device code

	C	M	DS	400	I	-	100	L
CE's power module								
For common cathode configuration								
DS for Schottky Barrier Diode								
Maximum average forward current, A								
I =Insulated Package								
Voltage rating (100 = 100V)								
L =Low VF Schottky diode								

Package Outline Information
C3 Package


Dimensions in mm